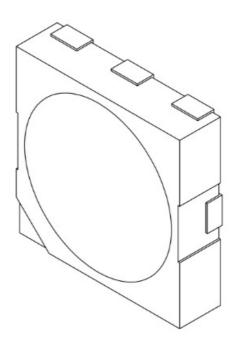
IRSMD5050-870-60-001



IRSMD5050-870-60-001

870nm HIGH POWER LED



Features

Chip size: 1.0×1.0mmNumber of Chips: 1pcPeak Wavelength: 870nm

Optical efficiency(typ.):1290mW

•Viewing half angle:60°

•Package: SMD Resin package

·Lens: Silicone Resin

Applications

- Machine Vision System
- •Light source for in-vehicle camera
- Infrared data communication

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Maximum Ratings (Tc=25℃)

| Parameter | Symbol | Values | Unit |
|-----------------------|-------------------|---------|------|
| Power Dissipation | P _D | 3800 | mW |
| Forward Current | I _F | 1000 | mA |
| Pulse Forward Current | I_{FP} | 3000 | mA |
| Reverse Voltage | V _R | 5 | V |
| Junction Temperature | Tj | 115 | °C |
| Operating Temperature | T _{opr} | -40~100 | °C |
| Storage Temperature | T_{stg} | -40~100 | °C |
| Thermal Resistance | R _{thja} | 10 | K/W |

^{**}Pulse Forward Current Condition: Duty 1% and Pulse Width=10us.

Optical and Electrical Characteristics (Tc=25°C)

| Parameter | Symbol | Min | Тур | Max | Unit | Test Condition |
|--------------------|-----------------|-----|------|-----|-------|-----------------------|
| Forward Voltage | V _F | | 3.3 | 3.8 | V | I _F =1A |
| | V _{FP} | | 3.9 | | V | I _{FP} =3A |
| Radiated Power | Po | | 1290 | | mW | I _F =1A |
| | | | 3770 | | mW | I _{FP} =3A |
| Radiant Intensity | I _E | | 2005 | | mW/sr | I _F =1A |
| | | | 5893 | | mW/sr | I _{FP} =3A |
| Peak Wavelength | λр | | 870 | | nm | I _F =1A |
| Half Width | Δλ | | 22 | | nm | I _F =1A |
| Viewing Half Angle | θ 1/2 | | ±60 | | deg | I _F =100mA |

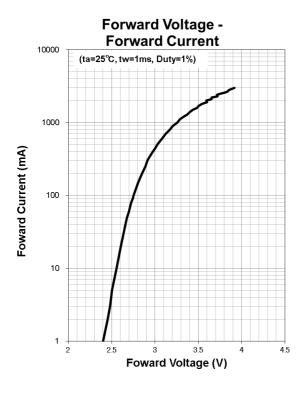
^{*}Radiated Power is measured by S3584-08.

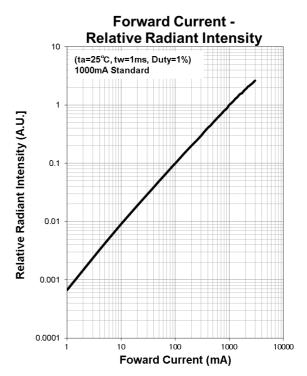
XSoldering condition: Soldering condition must be completed with 5 seconds at below 260℃

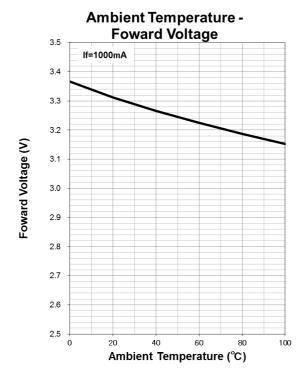
^{*}Radiant Intensity is measured by CIE127-2007 Condition B.

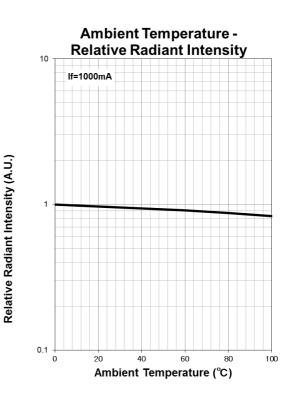
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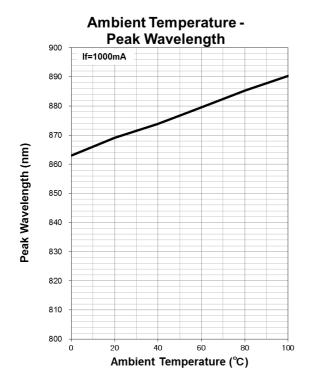
Typical Characteristic Curves

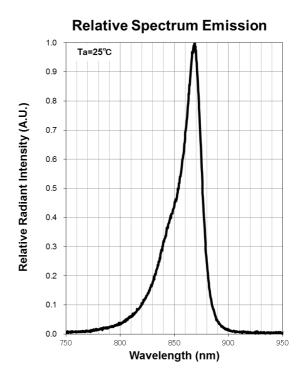


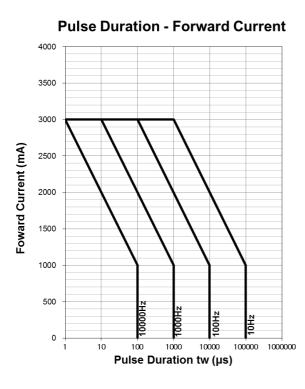


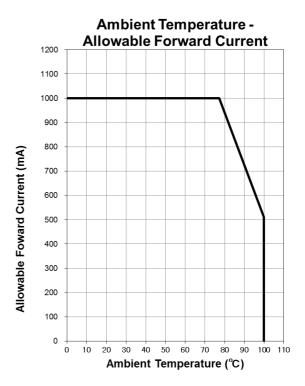




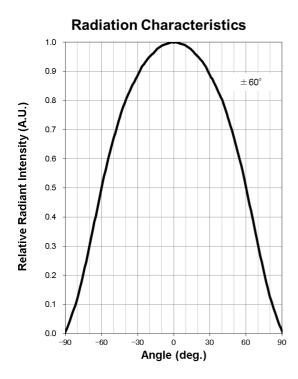






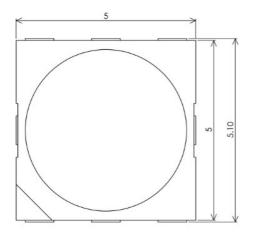


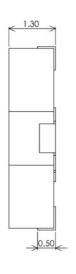
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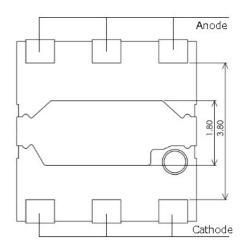


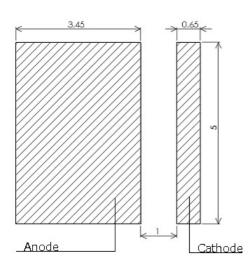
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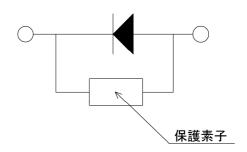
Outline and Internal Circuit











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RECOMMENDED METHODE OF STORAGE AND HANDLING

Storage Conditions

Before opening the moisture-proof Aluminum Bag

- Please keep at the condition of < 30°C and < 60% RH
- The maximum storage life is 12 months under these conditions.

After opening the moisture-proof Aluminum Bag

- Please store the aluminum bag and silica gel in a drying apparatus.
- The LED should go through the soldering process within 72 hours in a room with the condition of $5\sim30^{\circ}$ C and <50% RH
- Unused remaining LEDs and silica gel should be returned to the original aluminum bag. And please hermetically seal that bag.
- It is recommended to store the re-sealed bag in a drying apparatus at the condition of < 30% RH.
- 72 hours of long floor life does not included the time period which LEDs are stored in the moisture-proof Aluminum Bag. Even though, it is highly recommended to solder the LEDs as soon as after opening the aluminum bag.

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Product data and parameters in this brochure are typical values according to reasonably updated measurements.

Product data and parameters may vary by its application and operating time.

Products listed in this brochure are designed for the application of general electronic equipment or apparatus. Products are not designed for the applications of airplanes, aerospace equipment, automobiles, traffic control systems, nuclear power control systems, medical devices, safety devices and any other applications in which malfunction or failure may result in personal injury or death.

Oct. 2018